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Understanding Embedded - CPLDs (Complex Programmable Logic Devices)

Embedded - CPLDs, or Complex Programmable Logic Devices, are highly versatile digital logic devices used in electronic systems. These programmable components are designed to perform complex logical operations and can be customized for specific applications. Unlike fixed-function ICs, CPLDs offer the flexibility to reprogram their configuration, making them an ideal choice for various embedded systems. They consist of a set of logic gates and programmable interconnects, allowing designers to implement complex logic circuits without needing custom hardware.

Applications of Embedded - CPLDs

Details	
Product Status	Obsolete
Programmable Type	In System Programmable
Delay Time tpd(1) Max	7.5 ns
Voltage Supply - Internal	3V ~ 3.6V
Number of Logic Elements/Blocks	16
Number of Macrocells	256
Number of Gates	5000
Number of I/O	158
Operating Temperature	0°C ~ 70°C (TA)
Mounting Type	Surface Mount
Package / Case	208-BFQFP
Supplier Device Package	208-PQFP (28x28)
Purchase URL	https://www.e-xfl.com/product-detail/intel/epm3256aqc208-7n

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong

...and More Features

- PCI compatible
- Bus-friendly architecture including programmable slew-rate control
- Open–drain output option
- Programmable macrocell flipflops with individual clear, preset, clock, and clock enable controls
- Programmable power–saving mode for a power reduction of over 50% in each macrocell
- Configurable expander product–term distribution, allowing up to 32 product terms per macrocell
- Programmable security bit for protection of proprietary designs
- Enhanced architectural features, including:
 - 6 or 10 pin– or logic–driven output enable signals
 - Two global clock signals with optional inversion
 - Enhanced interconnect resources for improved routability
 - Programmable output slew–rate control
- Software design support and automatic place—and—route provided by Altera's development systems for Windows—based PCs and Sun SPARCstations, and HP 9000 Series 700/800 workstations
- Additional design entry and simulation support provided by EDIF 2 0 0 and 3 0 0 netlist files, library of parameterized modules (LPM), Verilog HDL, VHDL, and other interfaces to popular EDA tools from third–party manufacturers such as Cadence, Exemplar Logic, Mentor Graphics, OrCAD, Synopsys, Synplicity, and VeriBest
- Programming support with the Altera master programming unit (MPU), MasterBlasterTM communications cable, ByteBlasterMVTM parallel port download cable, BitBlasterTM serial download cable as well as programming hardware from third–party manufacturers and any in–circuit tester that supports JamTM Standard Test and Programming Language (STAPL) Files (.jam), Jam STAPL Byte-Code Files (.jbc), or Serial Vector Format Files (.svf)

General Description

MAX 3000A devices are low–cost, high–performance devices based on the Altera MAX architecture. Fabricated with advanced CMOS technology, the EEPROM–based MAX 3000A devices operate with a 3.3-V supply voltage and provide 600 to 10,000 usable gates, ISP, pin-to-pin delays as fast as 4.5 ns, and counter speeds of up to 227.3 MHz. MAX 3000A devices in the -4, -5, -6, -7, and -10 speed grades are compatible with the timing requirements of the PCI Special Interest Group (PCI SIG) *PCI Local Bus Specification, Revision 2.2.* See Table 2.

MAX 3000A devices contain 32 to 512 macrocells, combined into groups of 16 macrocells called logic array blocks (LABs). Each macrocell has a programmable—AND/fixed—OR array and a configurable register with independently programmable clock, clock enable, clear, and preset functions. To build complex logic functions, each macrocell can be supplemented with shareable expander and high—speed parallel expander product terms to provide up to 32 product terms per macrocell.

MAX 3000A devices provide programmable speed/power optimization. Speed-critical portions of a design can run at high speed/full power, while the remaining portions run at reduced speed/low power. This speed/power optimization feature enables the designer to configure one or more macrocells to operate at 50% or lower power while adding only a nominal timing delay. MAX 3000A devices also provide an option that reduces the slew rate of the output buffers, minimizing noise transients when non-speed-critical signals are switching. The output drivers of all MAX 3000A devices can be set for 2.5 V or 3.3 V, and all input pins are 2.5–V, 3.3–V, and 5.0-V tolerant, allowing MAX 3000A devices to be used in mixed-voltage systems.

MAX 3000A devices are supported by Altera development systems, which are integrated packages that offer schematic, text—including VHDL, Verilog HDL, and the Altera Hardware Description Language (AHDL)—and waveform design entry, compilation and logic synthesis, simulation and timing analysis, and device programming. The software provides EDIF 2 0 0 and 3 0 0, LPM, VHDL, Verilog HDL, and other interfaces for additional design entry and simulation support from other industry–standard PC– and UNIX–workstation–based EDA tools. The software runs on Windows–based PCs, as well as Sun SPARCstation, and HP 9000 Series 700/800 workstations.



For more information on development tools, see the MAX+PLUS II Programmable Logic Development System & Software Data Sheet and the Quartus Programmable Logic Development System & Software Data Sheet.

Functional Description

The MAX 3000A architecture includes the following elements:

- Logic array blocks (LABs)
- Macrocells
- Expander product terms (shareable and parallel)
- Programmable interconnect array (PIA)
- I/O control blocks

The MAX 3000A architecture includes four dedicated inputs that can be used as general–purpose inputs or as high–speed, global control signals (clock, clear, and two output enable signals) for each macrocell and I/O pin. Figure 1 shows the architecture of MAX 3000A devices.

For registered functions, each macrocell flipflop can be individually programmed to implement D, T, JK, or SR operation with programmable clock control. The flipflop can be bypassed for combinatorial operation. During design entry, the designer specifies the desired flipflop type; the Altera development system software then selects the most efficient flipflop operation for each registered function to optimize resource utilization.

Each programmable register can be clocked in three different modes:

- Global clock signal mode, which achieves the fastest clock–to–output performance.
- Global clock signal enabled by an active—high clock enable. A clock enable is generated by a product term. This mode provides an enable on each flipflop while still achieving the fast clock—to—output performance of the global clock.
- Array clock implemented with a product term. In this mode, the flipflop can be clocked by signals from buried macrocells or I/O pins.

Two global clock signals are available in MAX 3000A devices. As shown in Figure 1, these global clock signals can be the true or the complement of either of the two global clock pins, GCLK1 or GCLK2.

Each register also supports asynchronous preset and clear functions. As shown in Figure 2, the product–term select matrix allocates product terms to control these operations. Although the product–term–driven preset and clear from the register are active high, active–low control can be obtained by inverting the signal within the logic array. In addition, each register clear function can be individually driven by the active–low dedicated global clear pin (GCLRn).

All registers are cleared upon power-up. By default, all registered outputs drive low when the device is powered up. You can set the registered outputs to drive high upon power-up through the Quartus[®] II software. Quartus II software uses the NOT Gate Push-Back method, which uses an additional macrocell to set the output high. To set this in the Quartus II software, go to the Assignment Editor and set the **Power-Up Level** assignment for the register to **High**.

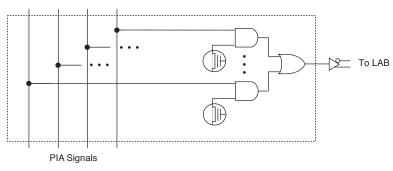
Parallel Expanders

Parallel expanders are unused product terms that can be allocated to a neighboring macrocell to implement fast, complex logic functions. Parallel expanders allow up to 20 product terms to directly feed the macrocell OR logic, with five product terms provided by the macrocell and 15 parallel expanders provided by neighboring macrocells in the LAB.

The Altera development system compiler can automatically allocate up to three sets of up to five parallel expanders to the macrocells that require additional product terms. Each set of five parallel expanders incurs a small, incremental timing delay (t_{PEXP}). For example, if a macrocell requires 14 product terms, the compiler uses the five dedicated product terms within the macrocell and allocates two sets of parallel expanders; the first set includes five product terms, and the second set includes four product terms, increasing the total delay by $2 \times t_{PEXP}$.

Two groups of eight macrocells within each LAB (e.g., macrocells 1 through 8 and 9 through 16) form two chains to lend or borrow parallel expanders. A macrocell borrows parallel expanders from lower–numbered macrocells. For example, macrocell 8 can borrow parallel expanders from macrocell 7, from macrocells 7 and 6, or from macrocells 7, 6, and 5. Within each group of eight, the lowest–numbered macrocell can only lend parallel expanders and the highest–numbered macrocell can only borrow them. Figure 4 shows how parallel expanders can be borrowed from a neighboring macrocell.

Figure 5. MAX 3000A PIA Routing



While the routing delays of channel–based routing schemes in masked or FPGAs are cumulative, variable, and path–dependent, the MAX 3000A PIA has a predictable delay. The PIA makes a design's timing performance easy to predict.

I/O Control Blocks

The I/O control block allows each I/O pin to be individually configured for input, output, or bidirectional operation. All I/O pins have a tri–state buffer that is individually controlled by one of the global output enable signals or directly connected to ground or $V_{CC}.$ Figure 6 shows the I/O control block for MAX 3000A devices. The I/O control block has 6 or 10 global output enable signals that are driven by the true or complement of two output enable signals, a subset of the I/O pins, or a subset of the I/O macrocells.

In-System Programmability

MAX 3000A devices can be programmed in–system via an industry–standard four–pin IEEE Std. 1149.1-1990 (JTAG) interface. In-system programmability (ISP) offers quick, efficient iterations during design development and debugging cycles. The MAX 3000A architecture internally generates the high programming voltages required to program its EEPROM cells, allowing in–system programming with only a single 3.3–V power supply. During in–system programming, the I/O pins are tri–stated and weakly pulled–up to eliminate board conflicts. The pull–up value is nominally 50 k Ω

MAX 3000A devices have an enhanced ISP algorithm for faster programming. These devices also offer an ISP_Done bit that ensures safe operation when in–system programming is interrupted. This ISP_Done bit, which is the last bit programmed, prevents all I/O pins from driving until the bit is programmed.

ISP simplifies the manufacturing flow by allowing devices to be mounted on a printed circuit board (PCB) with standard pick—and—place equipment before they are programmed. MAX 3000A devices can be programmed by downloading the information via in–circuit testers, embedded processors, the MasterBlaster communications cable, the ByteBlasterMV parallel port download cable, and the BitBlaster serial download cable. Programming the devices after they are placed on the board eliminates lead damage on high—pin—count packages (e.g., QFP packages) due to device handling. MAX 3000A devices can be reprogrammed after a system has already shipped to the field. For example, product upgrades can be performed in the field via software or modem.

The Jam STAPL programming and test language can be used to program MAX 3000A devices with in–circuit testers, PCs, or embedded processors.



For more information on using the Jam STAPL programming and test language, see *Application Note 88* (Using the Jam Language for ISP & ICR via an Embedded Processor), *Application Note 122* (Using Jam STAPL for ISP & ICR via an Embedded Processor) and AN 111 (Embedded Programming Using the 8051 and Jam Byte-Code).

The ISP circuitry in MAX 3000A devices is compliant with the IEEE Std. 1532 specification. The IEEE Std. 1532 is a standard developed to allow concurrent ISP between multiple PLD vendors.

Programming Sequence

During in-system programming, instructions, addresses, and data are shifted into the MAX 3000A device through the TDI input pin. Data is shifted out through the TDO output pin and compared against the expected data.

Programming a pattern into the device requires the following six ISP stages. A stand-alone verification of a programmed pattern involves only stages 1, 2, 5, and 6.

- Enter ISP. The enter ISP stage ensures that the I/O pins transition smoothly from user mode to ISP mode. The enter ISP stage requires 1 ms.
- Check ID. Before any program or verify process, the silicon ID is checked. The time required to read this silicon ID is relatively small compared to the overall programming time.
- 3. *Bulk Erase*. Erasing the device in-system involves shifting in the instructions to erase the device and applying one erase pulse of 100 ms.
- Program. Programming the device in-system involves shifting in the address and data and then applying the programming pulse to program the EEPROM cells. This process is repeated for each EEPROM address.
- Verify. Verifying an Altera device in-system involves shifting in addresses, applying the read pulse to verify the EEPROM cells, and shifting out the data for comparison. This process is repeated for each EEPROM address.
- 6. Exit ISP. An exit ISP stage ensures that the I/O pins transition smoothly from ISP mode to user mode. The exit ISP stage requires 1 ms.

Programming Times

The time required to implement each of the six programming stages can be broken into the following two elements:

- A pulse time to erase, program, or read the EEPROM cells.
- A shifting time based on the test clock (TCK) frequency and the number of TCK cycles to shift instructions, address, and data into the device.

The instruction register length of MAX 3000A devices is 10 bits. The IDCODE and USERCODE register length is 32 bits. Tables 8 and 9 show the boundary–scan register length and device IDCODE information for MAX 3000A devices.

Table 8. MAX 3000A Boundary-Sc	Table 8. MAX 3000A Boundary–Scan Register Length								
Device	Boundary–Scan Register Length								
EPM3032A	96								
EPM3064A	192								
EPM3128A	288								
EPM3256A	480								
EPM3512A	624								

Table 9. 32–Bit MAX 3000A Device IDCODE Value Note (1)											
Device		IDCODE (32 I	oits)								
	Version (4 Bits)	Part Number (16 Bits)	Manufacturer's Identity (11 Bits)	1 (1 Bit) (2)							
EPM3032A	0001	0111 0000 0011 0010	00001101110	1							
EPM3064A	0001	0111 0000 0110 0100	00001101110	1							
EPM3128A	0001	0111 0001 0010 1000	00001101110	1							
EPM3256A	0001	0111 0010 0101 0110	00001101110	1							
EPM3512A	0001	0111 0101 0001 0010	00001101110	1							

Notes:

- (1) The most significant bit (MSB) is on the left.
- (2) The least significant bit (LSB) for all JTAG IDCODEs is 1.



See Application Note 39 (IEEE 1149.1 (JTAG) Boundary–Scan Testing in Altera Devices) for more information on JTAG BST.

Programmable Speed/Power Control

MAX 3000A devices offer a power–saving mode that supports low-power operation across user–defined signal paths or the entire device. This feature allows total power dissipation to be reduced by 50% or more because most logic applications require only a small fraction of all gates to operate at maximum frequency.

The designer can program each individual macrocell in a MAX 3000A device for either high–speed or low–power operation. As a result, speed-critical paths in the design can run at high speed, while the remaining paths can operate at reduced power. Macrocells that run at low power incur a nominal timing delay adder (t_{LPA}) for the t_{LAD} , t_{LAC} , t_{IC} , t_{ACI} , t_{EN} , t_{CPPW} and t_{SEXP} parameters.

Output Configuration

MAX 3000A device outputs can be programmed to meet a variety of system–level requirements.

MultiVolt I/O Interface

The MAX 3000A device architecture supports the MultiVolt I/O interface feature, which allows MAX 3000A devices to connect to systems with differing supply voltages. MAX 3000A devices in all packages can be set for 2.5–V, 3.3–V, or 5.0–V I/O pin operation. These devices have one set of V_{CC} pins for internal operation and input buffers (VCCINT), and another set for I/O output drivers (VCCIO).

The VCCIO pins can be connected to either a 3.3–V or 2.5–V power supply, depending on the output requirements. When the VCCIO pins are connected to a 2.5–V power supply, the output levels are compatible with 2.5–V systems. When the VCCIO pins are connected to a 3.3–V power supply, the output high is at 3.3 V and is therefore compatible with 3.3-V or 5.0–V systems. Devices operating with V_{CCIO} levels lower than 3.0 V incur a nominally greater timing delay of t_{OD2} instead of t_{OD1} . Inputs can always be driven by 2.5–V, 3.3–V, or 5.0–V signals.

1	able I	1 summarızes	the MA	X 3000A	Multi V	olt I/C) supp	ort.
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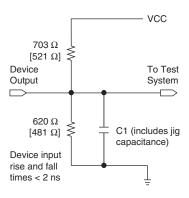
Table 11. MAX 300	Table 11. MAX 3000A MultiVolt I/O Support											
V _{CCIO} Voltage	V _{CCIO} Voltage Input Signal (V) Output Signal (V)											
	2.5	3.3	5.0	2.5	3.3	5.0						
2.5	✓	✓	✓	✓								
3.3	✓	✓	✓	✓	✓	✓						

Note:

(1) When $V_{\rm CCIO}$ is 3.3 V, a MAX 3000A device can drive a 2.5–V device that has 3.3–V tolerant inputs.

Figure 8. MAX 3000A AC Test Conditions

Power supply transients can affect AC measurements. Simultaneous transitions of multiple outputs should be avoided for accurate measurement. Threshold tests must not be performed under AC conditions. Large-amplitude, fastground-current transients normally occur as the device outputs discharge the load capacitances. When these transients flow through the parasitic inductance between the device ground pin and the test system ground, significant reductions in observable noise immunity can result. Numbers in brackets are for 2.5-V outputs. Numbers without brackets are for 3.3-V devices or outputs.



Operating Conditions

Tables 12 through 15 provide information on absolute maximum ratings, recommended operating conditions, DC operating conditions, and capacitance for MAX 3000A devices.

Table 1	Table 12. MAX 3000A Device Absolute Maximum Ratings Note (1)										
Symbol	Parameter	Min	Max	Unit							
V _{CC}	Supply voltage	With respect to ground (2)	-0.5	4.6	V						
VI	DC input voltage		-2.0	5.75	V						
I _{OUT}	DC output current, per pin		-25	25	mA						
T _{STG}	Storage temperature	No bias	-65	150	° C						
T _A	Ambient temperature	Under bias	-65	135	° C						
T_{J}	Junction temperature	PQFP and TQFP packages, under bias		135	° C						

 $V_{CCINT} = 3.3 V$

V_{CCIO} = 2.5 V

Temperature = 25 °C

150 I_{OL} 100 Typical I_O $V_{CCINT} = 3.3 V$ Output $V_{CCIO} = 3.3 V$ Current (mA) Temperature = 25 °C 50 I_{OH} 2 V_O Output Voltage (V) 2.5 V 150 I_{OL}

Figure 9. Output Drive Characteristics of MAX 3000A Devices

3.3 V

Power Sequencing & Hot-Socketing

Because MAX 3000A devices can be used in a mixed–voltage environment, they have been designed specifically to tolerate any possible power–up sequence. The $\rm V_{CCIO}$ and $\rm V_{CCINT}$ power planes can be powered in any order.

V_O Output Voltage (V)

Signals can be driven into MAX 3000A devices before and during power-up without damaging the device. In addition, MAX 3000A devices do not drive out during power-up. Once operating conditions are reached, MAX 3000A devices operate as specified by the user.

Altera Corporation 25

100

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Typical I_O

Current (mA)

Output

Table 17	7. EPM3032A Internal Timin	g Parameters (F	Part 2 of a	2) N	ote (1)				
Symbol	Parameter	Conditions		Speed Grade					
			-4		-7		-10		
			Min	Max	Min	Max	Min	Max	
t _{PIA}	PIA delay	(2)		0.9		1.5		2.1	ns
t_{LPA}	Low-power adder	(5)		2.5		4.0		5.0	ns

Table 18	3. EPM3064A External Timin	g Parameters	Note (1)					
Symbol	Parameter	Conditions			Speed	Grade			Unit
			_	4	-7		-10		
			Min	Max	Min	Max	Min	Max	
t _{PD1}	Input to non–registered output	C1 = 35 pF (2)		4.5		7.5		10.0	ns
t _{PD2}	I/O input to non–registered output	C1 = 35 pF <i>(2)</i>		4.5		7.5		10.0	ns
t _{SU}	Global clock setup time	(2)	2.8		4.7		6.2		ns
t _H	Global clock hold time	(2)	0.0		0.0		0.0		ns
t _{CO1}	Global clock to output delay	C1 = 35 pF	1.0	3.1	1.0	5.1	1.0	7.0	ns
t _{CH}	Global clock high time		2.0		3.0		4.0		ns
t _{CL}	Global clock low time		2.0		3.0		4.0		ns
t _{ASU}	Array clock setup time	(2)	1.6		2.6		3.6		ns
t _{AH}	Array clock hold time	(2)	0.3		0.4		0.6		ns
t _{ACO1}	Array clock to output delay	C1 = 35 pF (2)	1.0	4.3	1.0	7.2	1.0	9.6	ns
t _{ACH}	Array clock high time		2.0		3.0		4.0		ns
t _{ACL}	Array clock low time		2.0		3.0		4.0		ns
t _{CPPW}	Minimum pulse width for clear and preset	(3)	2.0		3.0		4.0		ns
t _{CNT}	Minimum global clock period	(2)		4.5		7.4		10.0	ns
f _{CNT}	Maximum internal global clock frequency	(2), (4)	222.2		135.1		100.0		MHz
t _{ACNT}	Minimum array clock period	(2)		4.5		7.4		10.0	ns
f _{ACNT}	Maximum internal array clock frequency	(2), (4)	222.2		135.1		100.0		MHz

Table 20	D. EPM3128A External 1	Timing Param	eters	Note (1)					
Symbol	Parameter	Conditions			Speed	Grade			Unit
			-5 -7			-1	10		
			Min	Max	Min	Max	Min	Max	
f _{ACNT}	Maximum internal array clock frequency	(2), (4)	192.3		129.9		98.0		MHz

Table 2	1. EPM3128A Internal Timing	g Parameters (I	Part 1 of	2) N	ote (1)				
Symbol	Parameter	Conditions			Speed	Grade			Unit
			_	·5	-	-7		10	
			Min	Max	Min	Max	Min	Max	
t _{IN}	Input pad and buffer delay			0.7		1.0		1.4	ns
t _{IO}	I/O input pad and buffer delay			0.7		1.0		1.4	ns
t _{SEXP}	Shared expander delay			2.0		2.9		3.8	ns
t _{PEXP}	Parallel expander delay			0.4		0.7		0.9	ns
t_{LAD}	Logic array delay			1.6		2.4		3.1	ns
t_{LAC}	Logic control array delay			0.7		1.0		1.3	ns
t _{IOE}	Internal output enable delay			0.0		0.0		0.0	ns
t _{OD1}	Output buffer and pad delay, slow slew rate = off $V_{CCIO} = 3.3 \text{ V}$	C1 = 35 pF		0.8		1.2		1.6	ns
t _{OD2}	Output buffer and pad delay, slow slew rate = off V _{CCIO} = 2.5 V	C1 = 35 pF		1.3		1.7		2.1	ns
t _{OD3}	Output buffer and pad delay, slow slew rate = on V _{CCIO} = 2.5 V or 3.3 V	C1 = 35 pF		5.8		6.2		6.6	ns
t _{ZX1}	Output buffer enable delay, slow slew rate = off $V_{CCIO} = 3.3 \text{ V}$	C1 = 35 pF		4.0		4.0		5.0	ns
t _{ZX2}	Output buffer enable delay, slow slew rate = off V _{CCIO} = 2.5 V	C1 = 35 pF		4.5		4.5		5.5	ns
t _{ZX3}	Output buffer enable delay, slow slew rate = on V _{CCIO} = 2.5 V or 3.3 V	C1 = 35 pF		9.0		9.0		10.0	ns
t_{XZ}	Output buffer disable delay	C1 = 5 pF		4.0		4.0		5.0	ns

Symbol	Parameter	Conditions		Speed	Grade		Unit
			_	7	-1		
			Min	Max	Min	Max	
t _{CNT}	Minimum global clock period	(2)		7.9		10.5	ns
f _{CNT}	Maximum internal global clock frequency	(2), (4)	126.6		95.2		MHz
t _{ACNT}	Minimum array clock period	(2)		7.9		10.5	ns
f _{ACNT}	Maximum internal array clock frequency	(2), (4)	126.6		95.2		MHz

Symbol	Parameter	Conditions		Speed	Grade		Unit
			-7		-10		
			Min	Max	Min	Max	
t _{IN}	Input pad and buffer delay			0.9		1.2	ns
t _{IO}	I/O input pad and buffer delay			0.9		1.2	ns
t _{SEXP}	Shared expander delay			2.8		3.7	ns
t _{PEXP}	Parallel expander delay			0.5		0.6	ns
t_{LAD}	Logic array delay			2.2		2.8	ns
t_{LAC}	Logic control array delay			1.0		1.3	ns
t _{IOE}	Internal output enable delay			0.0		0.0	ns
t _{OD1}	Output buffer and pad delay, slow slew rate = off $V_{CCIO} = 3.3 \text{ V}$	C1 = 35 pF		1.2		1.6	ns
t _{OD2}	Output buffer and pad delay, slow slew rate = off V _{CCIO} = 2.5 V	C1 = 35 pF		1.7		2.1	ns
t _{OD3}	Output buffer and pad delay, slow slew rate = on V _{CCIO} = 2.5 V or 3.3 V	C1 = 35 pF		6.2		6.6	ns
t _{ZX1}	Output buffer enable delay, slow slew rate = off V _{CCIO} = 3.3 V	C1 = 35 pF		4.0		5.0	ns
t _{ZX2}	Output buffer enable delay, slow slew rate = off V_{CCIO} = 2.5 V	C1 = 35 pF		4.5		5.5	ns

Table 23. EPM3256A Internal Timing Parameters (Part 2 of 2) Note (1)							
Symbol	Parameter	Conditions		Speed Grade			Unit
			-7		-10		
			Min	Max	Min	Max	
t_{ZX3}	Output buffer enable delay, slow slew rate = on V _{CCIO} = 2.5 V or 3.3 V	C1 = 35 pF		9.0		10.0	ns
t _{XZ}	Output buffer disable delay	C1 = 5 pF		4.0		5.0	ns
t _{SU}	Register setup time		2.1		2.9		ns
t_H	Register hold time		0.9		1.2		ns
t _{RD}	Register delay			1.2		1.6	ns
t _{COMB}	Combinatorial delay			0.8		1.2	ns
t _{IC}	Array clock delay			1.6		2.1	ns
t _{EN}	Register enable time			1.0		1.3	ns
t _{GLOB}	Global control delay			1.5		2.0	ns
t _{PRE}	Register preset time			2.3		3.0	ns
t _{CLR}	Register clear time			2.3		3.0	ns
t_{PIA}	PIA delay	(2)		2.4		3.2	ns
t_{LPA}	Low-power adder	(5)		4.0		5.0	ns

Table 24. EPM3512A External Timing Parameters Note (1)							
Symbol	Parameter	Conditions			Unit		
			-7			-10	
			Min	Max	Min	Max	
t _{PD1}	Input to non-registered output	C1 = 35 pF (2)		7.5		10.0	ns
t _{PD2}	I/O input to non-registered output	C1 = 35 pF (2)		7.5		10.0	ns
t _{SU}	Global clock setup time	(2)	5.6		7.6		ns
t _H	Global clock hold time	(2)	0.0		0.0		ns
t _{FSU}	Global clock setup time of fast input		3.0		3.0		ns
t _{FH}	Global clock hold time of fast input		0.0		0.0		ns
t _{CO1}	Global clock to output delay	C1 = 35 pF	1.0	4.7	1.0	6.3	ns
t _{CH}	Global clock high time		3.0		4.0		ns
t _{CL}	Global clock low time		3.0		4.0		ns
t _{ASU}	Array clock setup time	(2)	2.5		3.5		ns

Symbol	Parameter	Conditions	Speed Grade				Unit
			-7		-10		
			Min	Max	Min	Max	
t _{AH}	Array clock hold time	(2)	0.2		0.3		ns
t _{ACO1}	Array clock to output delay	C1 = 35 pF (2)	1.0	7.8	1.0	10.4	ns
t _{ACH}	Array clock high time		3.0		4.0		ns
t _{ACL}	Array clock low time		3.0		4.0		ns
t _{CPPW}	Minimum pulse width for clear and preset	(3)	3.0		4.0		ns
t _{CNT}	Minimum global clock period	(2)		8.6		11.5	ns
f _{CNT}	Maximum internal global clock frequency	(2), (4)	116.3		87.0		MHz
t _{ACNT}	Minimum array clock period	(2)		8.6		11.5	ns
f _{ACNT}	Maximum internal array clock frequency	(2), (4)	116.3		87.0		MHz

Table 25. EPM3512A Internal Timing Parameters (Part 1 of 2) Note (1)							
Symbol	Parameter	Conditions	nditions Speed Grad				Unit
			-7		-10		
			Min	Max	Min	Max	
t _{IN}	Input pad and buffer delay			0.7		0.9	ns
t _{IO}	I/O input pad and buffer delay			0.7		0.9	ns
t _{FIN}	Fast input delay			3.1		3.6	ns
t _{SEXP}	Shared expander delay			2.7		3.5	ns
t _{PEXP}	Parallel expander delay			0.4		0.5	ns
t_{LAD}	Logic array delay			2.2		2.8	ns
t _{LAC}	Logic control array delay			1.0		1.3	ns
t _{IOE}	Internal output enable delay			0.0		0.0	ns
t _{OD1}	Output buffer and pad delay, slow slew rate = off V _{CCIO} = 3.3 V	C1 = 35 pF		1.0		1.5	ns
t _{OD2}	Output buffer and pad delay, slow slew rate = off V _{CCIO} = 2.5 V	C1 = 35 pF		1.5		2.0	ns

Power Consumption

Supply power (P) versus frequency (f_{MAX}, in MHz) for MAX 3000A devices is calculated with the following equation:

$$P = P_{INT} + P_{IO} = I_{CCINT} \times V_{CC} + P_{IO}$$

The $P_{\rm IO}$ value, which depends on the device output load characteristics and switching frequency, can be calculated using the guidelines given in *Application Note 74 (Evaluating Power for Altera Devices)*.

The I_{CCINT} value depends on the switching frequency and the application logic. The I_{CCINT} value is calculated with the following equation:

 $I_{CCINT} =$

$$(A \times MC_{TON}) + [B \times (MC_{DEV} - MC_{TON})] + (C \times MC_{USED} \times f_{MAX} \times tog_{LC})$$

The parameters in the I_{CCINT} equation are:

 MC_{TON} = Number of macrocells with the Turbo BitTM option turned

on, as reported in the Quartus II or MAX+PLUS II Report

File (.rpt)

 MC_{DEV} = Number of macrocells in the device

MC_{USED} = Total number of macrocells in the design, as reported in

the RPT File

 f_{MAX} = Highest clock frequency to the device

tog_{LC} = Average percentage of logic cells toggling at each clock

(typically 12.5%)

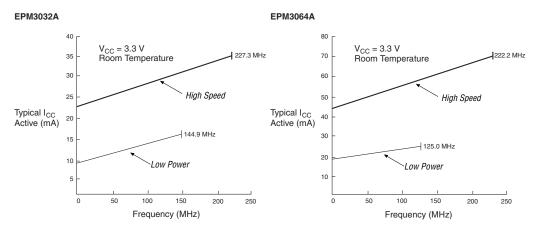
A, B, C = Constants (shown in Table 26)

Table 26. MAX 3000A I _{CC} Equation Constants						
Device	A	В	C			
EPM3032A	0.71	0.30	0.014			
EPM3064A	0.71	0.30	0.014			
EPM3128A	0.71	0.30	0.014			
EPM3256A	0.71	0.30	0.014			
EPM3512A	0.71	0.30	0.014			

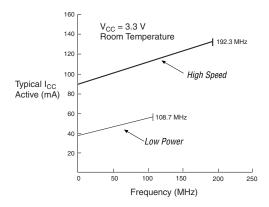
The I_{CCINT} calculation provides an I_{CC} estimate based on typical conditions using a pattern of a 16–bit, loadable, enabled, up/down counter in each LAB with no output load. Actual I_{CC} should be verified during operation because this measurement is sensitive to the actual pattern in the device and the environmental operating conditions.

Figures 12 and 13 show the typical supply current versus frequency for MAX 3000A devices.

Figure 12. I_{CC} vs. Frequency for MAX 3000A Devices



EPM3128A



Device Pin-Outs

See the Altera web site (http://www.altera.com) or the *Altera Digital Library* for pin–out information.

Figures 14 through 18 show the package pin-out diagrams for MAX 3000A devices.

Figure 14. 44-Pin PLCC/TQFP Package Pin-Out Diagram

Package outlines not drawn to scale.

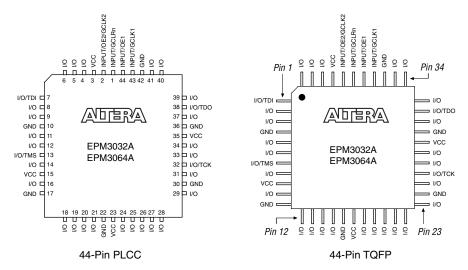
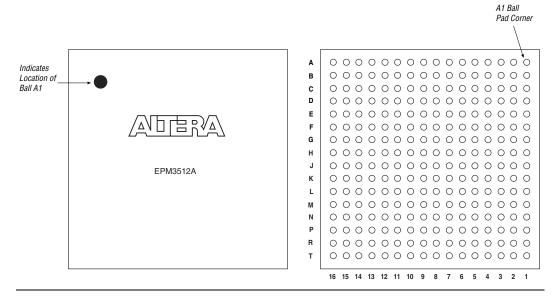


Figure 18. 256-Pin FineLine BGA Package Pin-Out Diagram

Package outline not drawn to scale.



Revision History

The information contained in the *MAX 3000A Programmable Logic Device Data Sheet* version 3.5 supersedes information published in previous versions. The following changes were made in the *MAX 3000A Programmable Logic Device Data Sheet* version 3.5:

Version 3.5

The following changes were made in the MAX 3000A Programmable Logic Device Data Sheet version 3.5:

■ New paragraph added before "Expander Product Terms".

Version 3.4

The following changes were made in the MAX 3000A Programmable Logic Device Data Sheet version 3.4:

■ Updated Table 1.